Digital transistor (built in resistor and zener diode) Driver (60V,1A) DTDG14GP

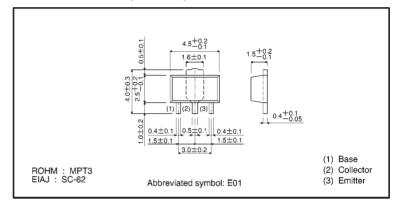
Features

- 1) High hee, typically hee = 750 at Vce = 2V at Ic = 0.5A.
- 2) Low saturation voltage, typically VCE(sat) = 0.4V at Ic/IB = 500mA / 5mA.
- Built-in zener diode to protect the transistor against reverse voltages when connected to allow load.

Structure

NPN digital transistor (with single built in resistor and zener diode)

External dimensions (Units: mm)

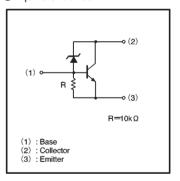


●Absolute maximum ratings (Ta = 25°C)

| Parameter | Symbol | Limits | Unit | |
|------------------------------|--------|------------------|---------|--|
| Collector-base voltage | Vсво | 60±10 | V | |
| Collector-emitter voltage | VCEO | VCEO 60±10 | | |
| Emitter-base voltage | VEBO | 5 | V | |
| Collector current | lc | 1 | А | |
| Collector current | ICP | Icp 2 A(F | | |
| Callantes navies disaination | D. | 0.5 | 10/ | |
| Collector power dissipation | Pc | 2 | W *2 | |
| Junction temperature | Tj | 150 | င | |
| Storage temperature | Tstg | −55~ +150 | င | |

- *1 Pw≤10ms, Duty cycle≤1/2
- *2 When mounted on a 40×40×0.7 mm ceramic board.

●Equivalent circuit



Transistors DTDG14GP

●Electrical characteristics (Ta = 25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--------------------------------------|----------|------|------|------|------|-----------------------------|
| Collector-base breakdown voltage | ВУсво | 50 | _ | 70 | ٧ | Ic=50 μ A |
| Collector-emitter breakdown voltage | BVCEO | 50 | _ | 70 | ٧ | Ic=1mA |
| Emitter-base breakdown voltage | ВУЕВО | 5 | _ | _ | ٧ | Iε=720 μ A |
| Collector cutoff current | Ісво | _ | _ | 0.5 | μΑ | V _{CB} =40V |
| Emitter cutoff current | ІЕВО | 300 | _ | 580 | μΑ | V _{EB} =4V |
| Collector-emitter saturation voltage | VCE(sat) | _ | _ | 0.4 | ٧ | Ic/Iв=500mA/5mA |
| DC current transfer ratio | hre | 300 | _ | _ | _ | VcE=2V, Ic=500mA |
| Emitter-base resistance | R | 7 | 10 | 13 | kΩ | _ |
| Transition frequency | fτ | _ | 80 | _ | MHz | VcE=5V, IE=-0.1A, f=30MHz * |

^{*} Transition frequency of the device

Packaging specifications

| | Package | MPT3 |
|----------|------------------------------|--------|
| | Packaging type | Taping |
| | Code | T100 |
| Part No. | Basic ordering unit (pieces) | 1000 |
| DTDG14GP | | 0 |

Electrical characteristic curves

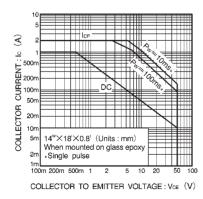


Fig.1 Safe operating area

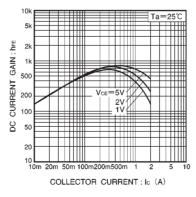


Fig.2 DC current gain vs. collector current

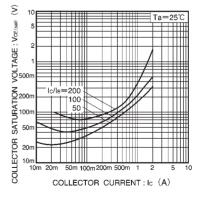


Fig.3 Collector-emitter saturation voltage vs. collector current